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STMicroelectronics STPS20SM60D

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STPS20SM60

Power Schottky rectifier

Features

- High current capability
- Avalanche rated
- Low forward voltage drop
- High frequency operation

Description

The STPS20SM60D is a single diode Schottky rectifier, suited for high frequency switch mode power supply.

Packaged in TO-220AC, this device is intended to be used in notebook, game station and desktop adapters, providing in these applications a good efficiency at both low and high load.

Symbol	Value
I _{F(AV)}	20 A
V _{RRM}	60 V
V _F (typ)	0.41 V
T _j (max)	150 °C

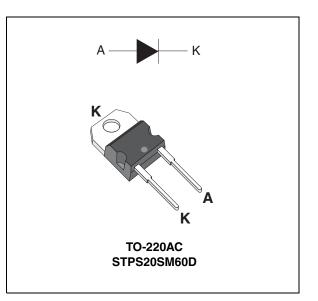
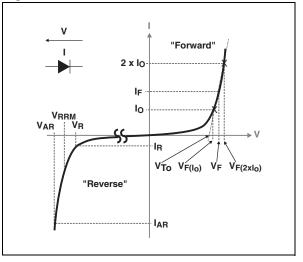


Figure 1. Electrical characteristics^(a)



a. V_{ARM} and I_{ARM} must respect the reverse safe operating area defined in *Figure 11*. V_{AR} and I_{AR} are pulse measurements (t_p < 1 μ s). V_R, I_R, V_{RRM} and V_F, are static characteristics



Characteristics

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1 Characteristics

Table 2.Absolute ratings (limiting values, at T_{amb} = 25 °C unless otherwise
specified)

Symbol	Parameter				Unit
V _{RRM}	Repetitive peak reverse voltage			60	V
I _{F(RMS)}	Forward rms current			60	Α
I _{F(AV)}	Average forward current, δ =	= 0.5	T _c = 130 °C	20	А
I _{FSM}	Surge non repetitive forward	d current	t _p = 10 ms sine-wave	400	А
P _{ARM} ⁽¹⁾	Repetitive peak avalanche p	etitive peak avalanche power $T_j = 25 \text{ °C}, t_p$			W
V _{ARM} ⁽²⁾	Maximum repetitive peak avalanche voltage	t _p < 1 μs, T _j < 1	80	V	
V _{ASM} ⁽²⁾	Maximum repetitive peak avalanche voltage	t _p < 1 μs, T _j < ⁻	80	V	
T _{stg}	Storage temperature range		-65 to +175	°C	
Тj	Maximum operating junction temperature ⁽³⁾			150	°C

1. For temperature or pulse time duration deratings, please refer to *Figure 4* and *5*. More details regarding the avalanche energy measurements and diode validation in the avalanche are provided in the application notes AN1768 and AN2025.

2. See Figure 11

3. $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal parameters

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case	1.3	°C/W

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _B ⁽¹⁾	Reverse leakage	T _j = 25 °C	VV	-	20	85	μΑ
'R`	current	T _j = 125 °C	$V_{R} = V_{RRM}$	-	15	50	mA
	$V_{F}^{(2)} Forward voltage drop \begin{cases} T_{j} = 25 \text{ °C} \\ T_{j} = 125 \text{ °C} \\ T_{j} = 25 \text{ °C} \\ T_{j} = 25 \text{ °C} \\ T_{j} = 25 \text{ °C} \\ T_{j} = 20 \text{ A} \end{cases}$	-	0.495	0.535			
$V_{-}^{(2)}$		T _j = 125 °C		-	0.410	0.460	v
VF`'		-	0.570	0.630	v		
		$T_j = 125 \ ^{\circ}C$	1F – 20 A	-	0.510	0.580	

1. Pulse test: $t_p = 5 \text{ ms}, \delta < 2\%$

2. Pulse test: $t_p = 380 \ \mu s, \ \delta < 2\%$

To evaluate the conduction losses use the following equation: P = 0.430 x $I_{F(AV)}$ + 0.0075 x $I_{F}^{2}(_{RMS)}$





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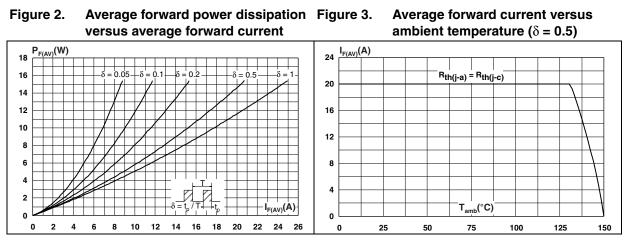


Figure 4. Normalized avalanche power derating versus pulse duration

Figure 5. Normalized avalanche power derating versus junction temperature

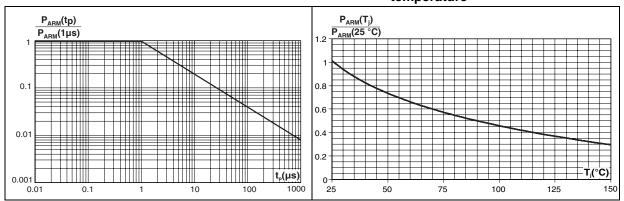
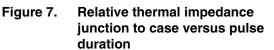
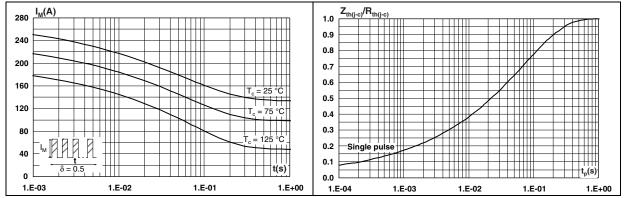


Figure 6. Non repetitive surge peak forward current versus overload duration (maximum values)









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10000 C(pF)

1000

100

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ั่ V_R(V)

100

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F = 1 MHz _{osc} = 30 mV_R

T_i = 25 °C

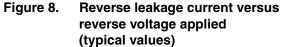
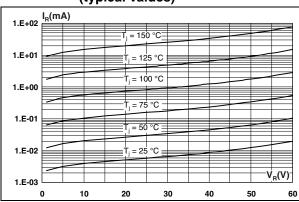
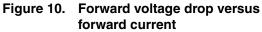
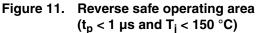


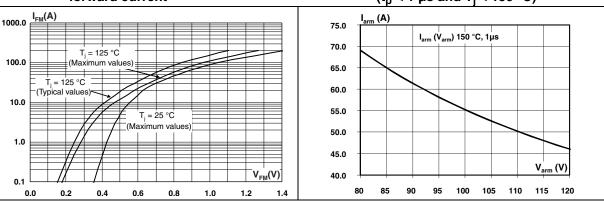
Figure 9. Junction capacitance versus reverse voltage applied (typical values)







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Package information

2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.4 to 0.6 N·m

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Table 5. TO-220AC dimensions

		Dimensions				
		Ref.	Millim	neters	Inc	hes
			Min.	Max.	Min.	Max.
		А	4.40	4.60	0.173	0.181
H2 A	→ .	С	1.23	1.32	0.048	0.051
		D	2.40	2.72	0.094	0.107
	L7	Е	0.49	0.70	0.019	0.027
	_ -	F	0.61	0.88	0.024	0.034
		F1	1.14	1.70	0.044	0.066
		G	4.95	5.15	0.194	0.202
		H2	10.00	10.40	0.393	0.409
		L2	16.40 typ.		0.645 typ.	
F. L4		L4	13.00	14.00	0.511	0.551
	M	L5	2.65	2.95	0.104	0.116
	E	L6	15.25	15.75	0.600	0.620
G		L7	6.20	6.60	0.244	0.259
		L9	3.50	3.93	0.137	0.154
		М	2.6	typ.	0.102	2 typ.
		Diam. I	3.75	3.85	0.147	0.151





Ordering information

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3 Ordering information

Table 6.Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS20SM60D	STPS20SM60D	TO-220AC	1.86 g	50	Tube

4 Revision history

Table 7.	Revision	history
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Date	Revision	Changes
25-Oct-2011	1	First issue.



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STPS20SM60

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